imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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IMH20TR1G

Dual Bias Resistor Transistor

NPN Surface Mount

- Low V_{CC} (sat) 80 mV max at IC/IB = 50 mA/2.5 mA
- High Current: $I_C = 600 \text{ mA max}$
- This is a Pb–Free Device

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector-Base Voltage	V _{(BR)CBO}	30	Vdc
Collector-Emitter Voltage	V _{(BR)CEO}	15	Vdc
Emitter-Base Voltage	V _{(BR)EBO}	5.0	Vdc
Collector Current – Continuous	Ι _C	600	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation*	PD	300	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

*Total for both Transistors.

Q1 + Q2: NPN

ELECTRICAL CHARACTERISTICS

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

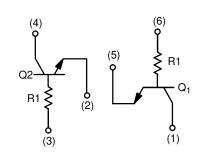
Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage $(I_C = 1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	15	-	Vdc
Collector–Base Breakdown Voltage ($I_C = 50 \ \mu Adc, I_E = 0$)	V _{(BR)CBO}	30	-	Vdc
Emitter–Base Breakdown Voltage ($I_E = 50 \ \mu Adc, I_C = 0$)	V _{(BR)EBO}	5.0	-	Vdc
Collector–Base Cutoff Current $(V_{CB} = 20 \text{ Vdc}, I_E = 0)$	I _{CBO}	-	0.5	μAdc
Emitter–Base Cutoff Current $(V_{EB} = 4.0 \text{ V}, I_C = 0)$	I _{EBO}	-	0.5	μAdc
DC Current Gain (Note 1) ($V_{CE} = 5.0$ Vdc, $I_C = 50$ mAdc)	h _{FE}	100	600	-
Collector–Emitter Saturation Voltage ($I_C = 50$ mAdc, $I_B = 2.5$ mAdc)	V _{CE(sat)}	-	80	mV
Input Resistance	R ₁	1.54	2.86	kΩ

1. Pulse Test: Pulse Width \leq 300 µs, D.C. \leq 2%.



ON Semiconductor®

http://onsemi.com



SC-74



SC-74R 318AA

Style 21

	Н	20	M	
20 =	Spec	ific I	Devi	ice Code

MARKING

DIAGRAM

H2 М = Date Code

ORDERING INFORMATION

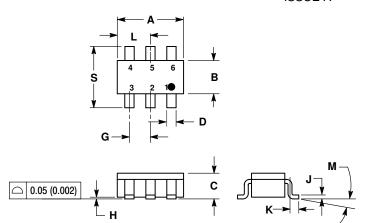
Device	Package	Shipping [†]	
IMH20TR1G	SC-74R	3000/Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

IMH20TR1G

PACKAGE DIMENSIONS

SC-74R CASE 318AA-01 **ISSUE A**



NOTES

3.

DIMENSIONING AND TOLERANCING PER 1.

ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

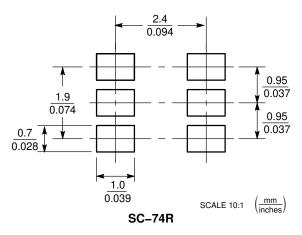
MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.1142	0.1220	2.90	3.10	
В	0.0512	0.0669	1.30	1.70	
С	0.0354	0.0433	0.90	1.10	
D	0.0098	0.0197	0.25	0.50	
G	0.0335	0.0413	0.85	1.05	
н	0.0005	0.0040	0.013	0.100	
J	0.0040	0.0102	0.10	0.26	
К	0.0079	0.0236	0.20	0.60	
L	0.0493	0.0649	1.25	1.65	
М	0 °	10°	0 °	10°	
S	0.0985	0.1181	2.50	3.00	

STYLE 21: PIN 1. COLLECTOR 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. EMITTER 1

6. BASE 1

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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